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Data Book

AU9340 USB Memory Stick Card Reader Controller Chip

Technical Reference Manual

Product Specification

Official Release

Revision 1.00

Public

Mar 2003



Data sheet status

Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.

Revision History

Date	Revision/Model	Description
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1.0 Introduction

1.1 Description

The AU9340 is a single chip integrated USB Memory Stick (MS) card reader controller. The AU9340 enabled Memory Stick card reader to be used as a removable storage disk in enormous data exchange applications between PC and PC or PC and various consumer electronic appliances.

The AU9340 reads digital data saved on memory stick while users manipulating electronic devices such as digital cameras, MP3 players, PDAs and mobile phones... etc. By the AU9340, users can transfer information such as data, graphics, texts or digital images from one electronic device to another quickly and easily. With AU9340, users' knowledge will be further enhanced by the Plug-and-Play nature built into latest operation systems such as Windows 2000/XP and Mac OS X.

By integrating of various analog components, the AU9340 is the most powerful and most effective solution for Memory Stick card .

1.2 Features

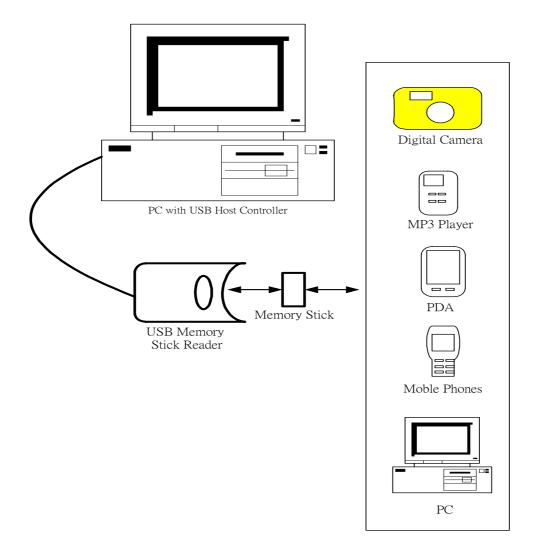
- Fully compliant with USB v1.1 specification and USB Device Class Definition for Mass Storage, Bulk-Transport v1.0
- Fully compliant with Memory Stick (MS) v1.3 Specification.
- Work with default driver from Windows ME, Windows 2000, Windows XP, Mac OS 9.1, and Mac OS X. Windows 98 is supported by mass storage class driver from Alcor.
- Ping-pong FIFO implementation for concurrent bus operation.
- Dedicated hardware engine for MS bus operation, average throughput over 1MB/sec for read, 680KB/sec for write operation.
- Support multiple sectors transfer up to 128MB to optimize performance
- Support optional external EEPROM for USB VID, PID and string customization
- Capable of handling 8 sets of built-in PID, VID and strings to minimize inventory control and improve lead production lead time
- LED for bus activity indication.
- Integrated power switch and power management circuit to meet USB 500uA power consumption during suspend with MS card in the slot.
- Runs at 12MHz, built-in 48 MHz PLL
- Built-in 3.3V regulator
- 28-pin SSOP package



2.0 Application Block Diagram

Following is the application diagram of a typical memory stick card reader. By connecting the reader to a PC through USB bus, the AU9340 is acting as a bridge between the flash memory card from digital camera, MP3 player, PDA or mobile phone and PC.





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3.0 Pin Assignment

The AU9340 is packed in 28-SSOP form factor. The following figure shows signal name for each pin and the table in the following page describes each pin in detail

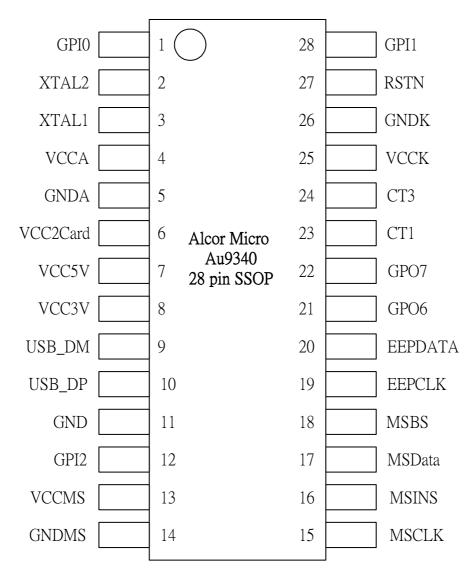


Figure 3.1 Pin Assignment Diagram



PIN	Name	Input/Output	Description
1	GPI0	Input	Internal ROM selection, Connect to GND or VCC
2	XTAL2	Output	Crystal Oscillator Output (12 MHz)
3	XTAL1	Input	Crystal Oscillator Input (12 MHz)
4	VCCA	Power	Analog 3.3 Input
5	GNDA	GND	Ground
6	VCC2Card	Output	Power to MS Card
7	VCC5V	Power	5V power supply
8	VCC3V	Power	Regulator 3.3V output for VCCA and VCCK.
9	USB_DM	Input/Output	USB D-
10	USB_DP	Input/Output	USB D+
11	GND	GND	Ground
12	GPI2	Input	Internal ROM selection, Connect to GND or VCC
13	VCCMS	Input	InPut VCC3V to MS Power
14	GNDMS	Input	InPut Ground to MS Power Ground
15	MSCLK	Output	Connect to MS Card SCLK. #8
16	MSINS	Input	Connect to MS Card INS Pin #6
17	MSData	Input/Output	Connect to MS Card Data Pin #4
18	MSBS	Output	Connect to MS Card BS Pin #2
19	EEPCLK	Input	EEPROM clock
20	EEPDATA	Input	EEPROM data
21	GPO6	Output	NC
22	GPO7	Output	Connect to LED
23	CT1	Input	Connect to GND
24	CT3	Input	Connect to Ground
25	VCCK	Power	3.3 Core Voltage Input
26	GNDK	GND	Ground
27	RSTN	Input	Connect to VCC3
28	GPI1	Input	Internal ROM selection, Connect to GND or VCC

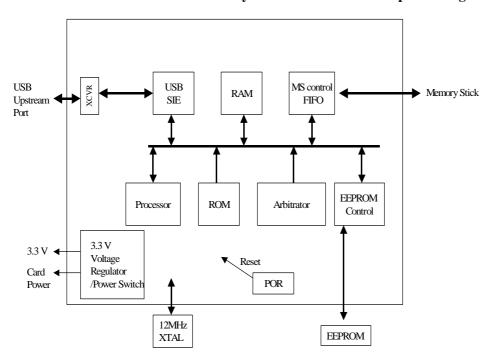
Table 3.1 Pin Descriptions



4.0 System Architecture and Reference Design

4.1 AU9340 Block Diagram

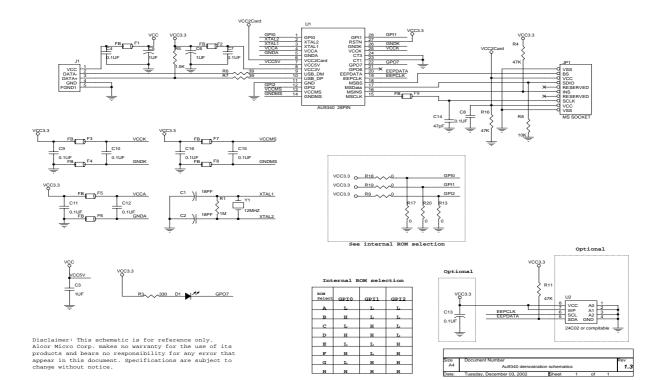
Figure 4.1 AU9340 Block Diagram



Alcor Micro - AU9340 Flash Memory Card Reader Controller Chip Block Diagram



4.2 Sample Schematics





5.0 Electrical Characteristics

5.1 Absolute Maximum Ratings

Table 5.1 Absolute Maximum Ratings

SYMBOL	PARAMETER	RATING	UNITS
V _{cc}	Power Supply	Power Supply -0.3 to 6.0	
V _{IN}	Input Voltage	-0.3 to VCC+0.3	V
V _{OUT}	Output Voltage	-0.3 to VCC+0.3	V
T _{STG}	Storage Temperature	-40 to 125	°C

5.2 Recommended Operating Conditions

SYMBOL	PARAMETER	MIN	ТҮР	МАХ	UNITS
V _{cc}	Power Supply	4.5	5.0	5.5	V
V _{IN}	Input Voltage	0		V_{cc}	V
T _{OPR}	Operating Temperature	-5		85	°C

Table 5.2 Recommended Operating Conditions

5.3 General DC Characteristics

Table 5.3 General DC Characteristics

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
$I_{\rm IL}$	Input low current	no pull-up or pull-down	-1		1	μA
I _{IH}	Input high current	no pull-up or pull-down	-1		1	μA
l _{oz}	Tri-state leakage current		-10		10	μΑ
C _{IN}	Input capacitance			4		ρF
C _{OUT}	Output capacitance			4		ρF
CBID	Bi-directional buffer capacitance			4		ρF



5.4 DC Electrical Characteristics for 5 volts operation

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V _{IL}	Input Low Voltage	TTL			0.8	V
VIL	Input Low Voltage	CMOS			$0.3*V_{CC}$	V
V _{IL}	Schmitt input Low Voltage	TTL		1.10		V
VIL	Schmitt input Low V oltage	CMOS		1.84		V
V _{IH}	Input High Voltage	TTL	2.2			V
VIH	Input Hight Voltage	CMOS	$0.7{}^{\star}V_{\text{CC}}$			V
VIH	Schmitt input High Voltage	TTL		1.87		V
VIH	Schmitt input High Voltage	CMOS		3.22		V
V _{OL}	Output low voltage	I _{OL} =2, 4, 8, 12, 16, 24 mA			0.4	V
V _{OH}	Output high voltage	I _{OH} =2, 4, 8, 12, 16, 24 mA	3.5			V
Rı	Input Pull-up/down resistance	$ViI=0_V$ or $Vih=V_{CC}$		50		KΩ

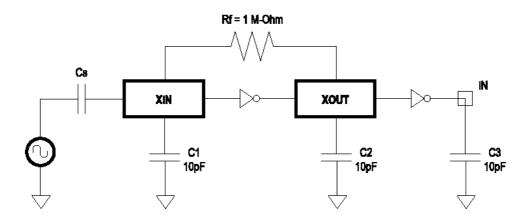
Table 5.4 DC Electrical Characteristics for 5 volts operation

(Under Recommended Operating Conditions and $V_{\text{CC}}{=}4.5v$ ~ 5.5v , $Tj{=}{-}40^{\circ}\text{C}$ to + 85°C)

5.5 Crystal Oscillator Circuit Setup for Characterization

The following setup was used to measure the open loop voltage gain for crystal oscillator circuits. The feedback resistor serves to bias the circuit at its quiescent operating point and the AC coupling capacitor, Cs, is much larger than C1 and C2.

Figure 5.1 Crystal Oscillator Circuit Setup for Characterization



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5.6 USB Transceiver Characteristics RECOMMENDED OPERATING CONDITIONS

Table 5.5 USB Transceiver Characteristics

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V _{cc}	DC supply voltage		3.0	3.6	V
Vı	DC input voltage range		0	5.5	V
V _{I/O}	DC input range for I/Os		0	V _{cc}	V
Vo	DC output voltage range		0	V_{CC}	V
Т _{амв}	Operating ambient temperature range in free air	See DC and AC characteristics for individual device	0	70	°C

ABSOLUTE MAXIMUM RATINGS (Notes 1 and 2)

In accordance with the Absolute Maximum Rating System, Voltages are referenced to GND (Ground=0v)

SYMBOL	PARAMETER	CONDITIONS	LIN	NITS	UNIT			
			MIN	MAX				
V _{cc}	DC supply voltage		-0.5	+6.5	V			
I _{IK}	DC input diode current	Vi<0		-50	mA			
V,	DC input voltage	Note 3	-0.5	+5.5	V			
V _{1/0}	DC input voltage range for I/Os		-0.5	Vcc +0.5	V			
І _{ок}	DC output diode current	Vo> Vcc or Vo<0		+/-50	mA			
Vo	DC output voltage	Note 3	-0.5	Vcc +0.5	V			
I _o	DC output source sink current for VP/VM and RCV pins	Vo=0 to Vcc		+/-15	mA			
I _o	DC output source or sink current for D+/D- pins	Vo= 0 to Vcc		+/-50	mA			
I _{cc} , I _{gnd}	DC Vcc or GND current			+/-100	mA			
Т _{sto}	Storage temperature range		-60	+150	°C			
P _{TOT}	Power dissipation per package				mW			

Table 5.6 Absolute Maximum Ratings

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
- 3. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.



DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (Ground=OV).

Table 5.7 DC Electrical Characteristics									
				LIMITS					
SYMBOL	PARAMETER	TEST CONDITIONS		<u>C to +8</u>	5 [°] C	UNIT			
			MIN	TYP	MAX				
VHYS	Hysteresis on inputs	Vcc=3.0V to 3.6V (Note 3)	0.3	0.4	0.5	V			
VIH	HIGH level input	Vcc=3.0V to 3.6V (Note 3)		1.5	2.0	V			
VIL	LOW level input	Vcc=3.0V to 3.6V (Note 3)	0.8	1.1		V			
RoH	Output impedance (HIGH state)	Note 2	28	34	43	ohm			
RoL	Output impedance (LOW state)	Note 2	28	35	43	ohm			
VOH	HIGH level output (Note 3)	Vcc=3.0V Io=6mA Vcc=3.0V Io=4mA Vcc=3.0V Io=100µA	2.2 2.4 2.8	2.7		V			
VOL	LOW level output (Note 3)	Vcc=3.0V Io=6mA Vcc=3.0V Io=4mA Vcc=3.0V Io=100µA		0.3	0.7 0.4 0.2	V			
IQ	Quiescent supply current	Vcc=3.6V VI=Vcc or GND Io=0		330	600	μA			
Isup	Supply current in suspend	Vcc=3.6V VI=Vcc or GND Io=0			70	μA			
IFS	Active supply current (Full Speed)	Vcc=3.3V		9	14	mA			
ILS	Active supply current (Low Speed)	Vcc=3.3V		2		mA			
ILeak	Input leakage current	Vcc=3.6V VI=5.5V or GND, not for I/O Pins		+/-0.1	+/-0.5	μΑ			
IOFF	3-state output OFF-state current	Vi=Vih or ViL; Vo=Vcc or GND			+/-10	μΑ			

Table 5.7 DC Electrical Characteristics

NOTES:

- 1. All typical values are at Vcc=3.3V and Tamb= $25^{\circ}C$.
- 2. This value includes an external resistor of 24 ohm +/-1%. See "Load D+ and D-" diagram for testing details.
- 3. All signals except D+ and D-.



AC ELECTRICAL CHARACTERISTICS

GND=0V, $t_{\scriptscriptstyle R}$ = $t_{\scriptscriptstyle F}$ =3.0 ns; $C_{\scriptscriptstyle L}$ =50 pF; RL=500 Ohms

Table 5.8 AC Electrical Characteristics									
				LIN	NITS (T	амв)			
SYMBOL	PARAMETER	NAVEFORM		C to +25			+70 [°] C	UNIT	
			MIN	TYP	MAX	MIN	MAX		
tpLH tpHL	VMO/VPO to D+/D- Full Speed	1	0 0		12 12	0 0	14 14	ns	
trise tfall	Rise and Fall Times Full Speed	2	4 4	9 9	20 20	4 4	20 20	ns	
tRFM	Rise and Fall Time Matching Full Speed		90		110	90	110	%	
tpLH tpHL	VMO/VPO to D+/D- Low Speed	1		120 120	300 300		300 300	ns	
trise tfall	Rise and Fall Times Low Speed	2	75 75		300 200	75 75	300 200	ns	
tRFM	Rise and Fall Time Matching Low Speed		70		130	70	130	%	
tpLH tpHL	D+/D- to RCV	3		9 9	16 16		16 16	ns	
tpLH tpHL	D+/D- to VP/VM	1		4 4	8 8		8 8	ns	
tpHZ tpZH tpLZ tpZL	OE# to D+/D- RL = 500ohm	4			12 12 10 10		12 12 10 10	ns	
tsu	Setup for SPEED	5	0					ns	
Vcr	Crossover point ¹	3	1.3		2.0	1.3	2.0	V	

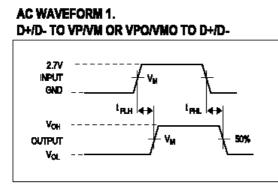
NOTES:

1. The crossover point is in the range of 1.3V to 2.5V for the low speed mode with a 50 pF capacitance.

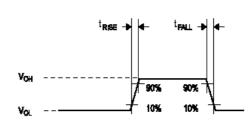


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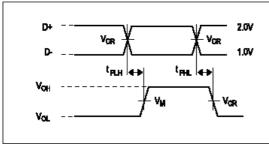




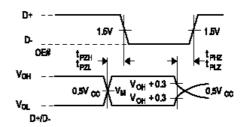


AC WAVEFORM 3.

D+/D- TO RCV

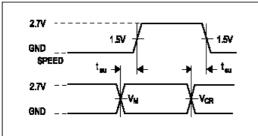


AC WAVEFORM 4. OE# TO D/+/D-

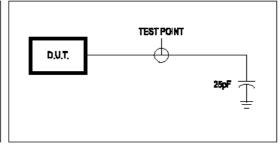


AC WAVEFORM 5. SETUP FOR SPEED

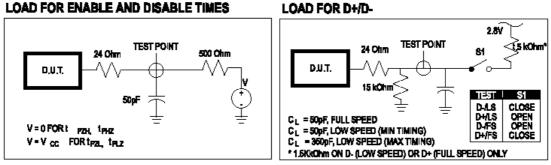
TEST CIRCUIT 2.



TEST CIRCUIT 1. LOAD FOR VM/VP AND RCV



TEST CIRCUIT 3. LOAD FOR D+/D-



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5.7 ESD Test Results

Test Description: ESD Testing was performed on a Zapmaster system using the Human-Body-Model (HBM) and Machine-Model (MM), according to MIL-STD 883 and EIAJ IC-121 respectively.

- Human-Body-Model stresses devices by sudden application of a high voltage supplied by a 100pF capacitor through 1.5k-ohm resistance.
- Machine-Model stresses devices by sudden application of a high voltage supplied by a 200pF capacitor through very low (0 ohm) resistance.

Test circuit & condition

- Zap Interval: 1 second
- Number of Zaps: 3 positive and 3 negative at room temperature
- Criteria: I-V Curve Tracing

	Table 5.7 ESD Data								
Model	Mode	s/s	Target	Results					
HBM	Vdd, Vss, I/C	15	6000V	PASS					
MM	Vdd, Vss, I/C	15	200V	PASS					

Table 5.9 ESD Data



5.8 Latch-Up Test Results

Test Description: Latch-Up testing was performed at room ambient using an IMCS-4600 system which applies a stepped voltage to one pin per device with all other pins open except Vdd and Vss which were biased to 5Volts and ground respectively.

Testing was started at 5.0V (Positive) or 0V (Negative), and the DUT was biased for 0.5 seconds.

If neither the PUT current supply nor the device current supply reached the predefined limit (DUT=00mA, Icc=100mA), then the voltage was increased by 0.1Volts and the pin was tested again.

This procedure was recommended by the JEDEC JC-40.2 CMOS Logic standardization committee.

Notes:

- 1. DUT: Device Under Test.
- 2. PUT: Pin Under Test.

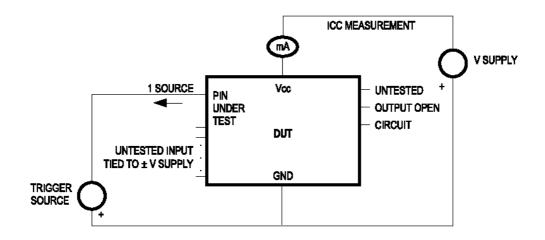
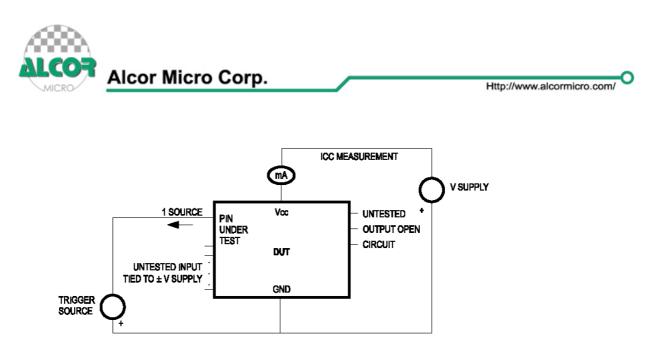
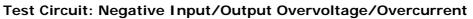


Figure 5.3 Latch-Up Test Results

Test Circuit: Positive Input/Output Overvoltage/Overcurrent





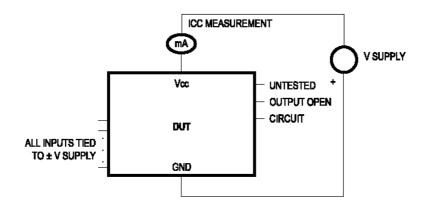




Table	5.10	Latch-Up	Data
-------	------	----------	------

Mode		Voltage (V)/Current (mA)	S/S	Results
Valtaga	+	11.0	5	Pass
Voltage	-	11.0	5	Pass
Current	+	200	5	Pass
Current	-	200	5	Pass
V	dd - Vxx	9.0	5	Pass



6.0 Mechanical Information

Following diagrams show the dimensions of the AU9340 28-pin SSOP. Measurements are in inches. Dimensions do not include mold flash and dambar protrusion; allowable mold flash is 0.010 inch.

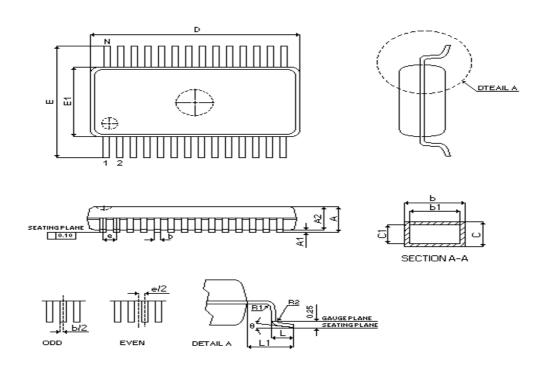


Figure 6.1 Mechanical Information Diagram

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R REV.	DESCRIPTION	BY	DATE
ORIG.	1. REGENERATED FROM PO-P402 VERSION"A"	JIMMY	97.04.21
	2. ADD GAUGE PLANE		
1	ADD CROSS SECTIONA-A" DRAWING	STEVEN	97.07.31
2	MODIFY 0.020 TO 0.002	IRIS	97.08.21
3	ADD E-PIN	IRIS	98.06.10
	CHANGE PIN "I" DOT DIMENSION		

SYMBOL	COMMON DIMENSION MILLIMETERS			COMMON DIMENSION		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α			2			0.079
A1	0.05			0.002		
A2	1.65	1.75	1.85	0.065	0.069	0.073
b	0.22		0.38	0.009		0.015
b1	0.22	0.3	0.33	0.009	0.012	0.013
С	0.09		0.25	0.004		0.01
c1	0.09	0.15	0.21	0.004	0.006	0.008
D	9.90	10.20	10.50	0.390	0.402	0.413
E	7.4	7.8	8.2	0.291	0.307	0.323
E1	5	5.3	5.6	0.197	0.209	0.22
е	0.65 BSC				0.0256 BSC	
L	0.55	0.75	0.95	0.021	0.03	0.037
L1	0.25 REF.			0.050 REF.		
R1	0.09			0.004		
R2	0.09			0.004		
θ	0	40	80	0	40	80

N	14	16	18	20	24	28
0 ± 0.30	6.20	6.20	7.20	7.20	8.20	10.20
JEDEC NO.	MO-150	MO-150	MO-150	MO-150	MO-150	MO-150
JEDEC NO.	AB	AC	AD	AE	AG	AH

UNLESS	DECMAL	ANGULAR		UNIT	мм	SCALF: 10: 1
OTHERWISE	X ±		ORENT SEMCONOUCTOR ELECTRONICS	UNTI	IVIIVI	SCALE. TO. T
	xx ±.10	±3°			NE1	
SPECIFIED	xxx ±.05			SHEET: 1 OF1		
DRAWN	IRIS 98.06.10		TITLE	FILE:PD-P503C A		A3
CHECKED			SSOP 14/16/20/21/28L(209MIL)	DWG. NO.:		
APPROVED			PACKAGE OUTLINE		PD-P50	03C



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